

### GENERAL DESCRIPTION

The PT4115E is a continuous conduction mode inductive step-down converter, designed for driving single or multiple series connected LED efficiently from a voltage source higher than the total LED chain voltage. The device operates from an input supply between 6V and 50V and provides an externally adjustable output current of up to 1.5A.

The PT4115E includes the power switch and a high-side output current sensing circuit, which uses an external resistor to set the nominal average output current, and a dedicated DIM input accepts either a DC voltage or a wide range of pulsed dimming. Applying a voltage of 0.3V or lower to the DIM pin turns the output off and switches the device into a low current standby state.

The PT4115E is available in SOT89-5 package.


### FEATURES

- Simple low parts count
- Wide input voltage range: 6V to 50V
- High efficiency (up to 97%)
- Up to 1.5A output current
- Single pin on/off and brightness control using DC voltage or PWM
- Up to 1MHz switching frequency
- Typical 3% output current accuracy
- Inherent open-circuit LED protection
- Inherent Rcs open protection
- High-Side Current Sense
- Hysteretic Control: No need compensation
- Adjustable Constant LED Current
- Thermal shutdown

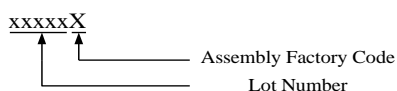
### APPLICATIONS

- Low voltage halogen replacement LEDs
- Automotive lighting
- Low voltage industrial lighting
- LED back-up lighting
- Illuminated signs
- SELV lighting
- LCD TV backlighting

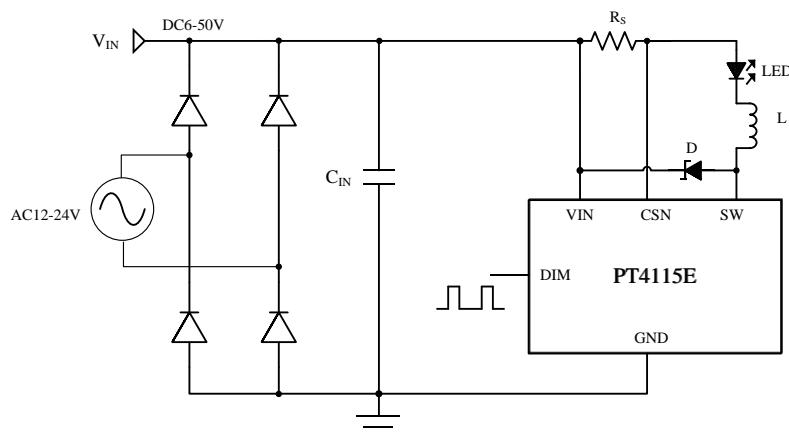
### ORDERING INFORMATION

PACKAGE	TEMPERATURE RANGE	ORDERING PART NUMBER	TRANSPORT MEDIA	MARKING
SOT89-5	-40 °C to 85 °C	PT4115EE89E	Tape and Reel 1000 units	 PT4115E xxxxxX

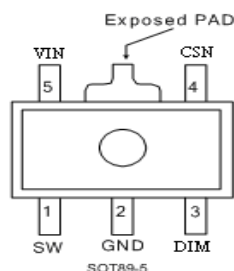
Note:



### TYPICAL APPLICATION CIRCUIT



### PIN ASSIGNMENT



### PIN DESCRIPTIONS

SOT89-5 PIN No.	PIN NAMES	DESCRIPTION
1	SW	Switch Output. SW is the drain of the internal N-Ch MOSFET switch.
2	GND	Signal and power ground. Connect directly to ground plane.
3	DIM	Logic level dimming input. Drive DIM low to turn off the current regulator. Drive DIM high to enable the current regulator.
4	CSN	Current sense input
5	VIN	Input Supply Pin. Must be locally bypassed.
	Exposed PAD	Internally connected to GND. Mount on board for lower thermal resistance.

### ABSOLUTE MAXIMUM RATINGS (note1)

SYMBOL	ITEMS	VALUE	UNIT
$V_{IN}$	Supply Voltage	-0.3~55	V
SW	Drain of the internal power switch	-0.3~55	V
CSN	Current sense input (Respect to VIN)	+0.3~(-6.0)	V
DIM	Logic level dimming input	-0.3~6	V
$I_{SW}$	Switch output current	1.5	A
$P_{DMAX}$	Power Dissipation (Note 2)	1.5	W
$P_{TR}$	Thermal Resistance, SOT89-5 $\theta_{JA}$	45	°C /W
$T_J$	Operation Junction Temperature Range	-40 to 150	°C
$T_{STG}$	Storage Temperature	-55 to 150	°C
	ESD Susceptibility (Note 3)	2	kV

**RECOMMENDED OPERATING RANGE**

SYMBOL	ITEMS	VALUE	UNIT
V <sub>IN</sub>	V <sub>DD</sub> Supply Voltage	6 ~ 50	V
T <sub>OPT</sub>	Operating Temperature	-40 to +85	°C

**Note 1:** Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Recommended Operating Range indicates conditions for which the device is functional, but do not guarantee specific performance limits. Electrical Characteristics state DC and AC electrical specifications under particular test conditions which guarantee specific performance limits. This assumes that the device is within the Operating Range. Specifications are not guaranteed for parameters where no limit is given, however, the typical value is a good indication of device performance.

**Note 2:** The maximum power dissipation must be derated at elevated temperatures and is dictated by T<sub>JMAX</sub>, θ<sub>JA</sub>, and the ambient temperature T<sub>A</sub>. The maximum allowable power dissipation is P<sub>DMAX</sub> = (T<sub>JMAX</sub> - T<sub>A</sub>) / θ<sub>JA</sub> or the number given in Absolute Maximum Ratings, whichever is lower.

**Note 3:** Human body model, 100pF discharged through a 1.5kΩ resistor.

### ELECTRICAL CHARACTERISTICS (Note 4, 5)

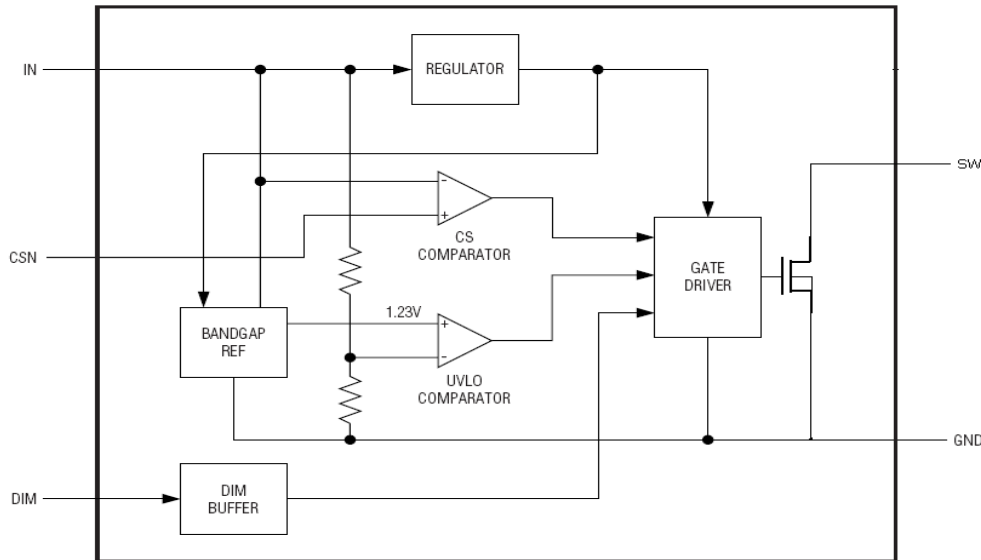
The following specifications apply for  $V_{IN}=24V$ ,  $T_A=25^{\circ}C$ , unless specified otherwise.

SYMBOL	ITEMS	CONDITIONS	Min.	Typ.	Max.	UNIT
$V_{IN}$	Input Voltage		6		50	V
$V_{UVLO}$	Under voltage lock out	$V_{IN}$ rising		4.5		V
$V_{UVLO\_HYS}$	UVLO hysteresis	$V_{IN}$ falling		0.3		V
$F_{SW}$	Max. Switching Frequency				1	MHz
<b>Current Sense</b>						
$V_{CSN}$	Mean current sense threshold voltage	$V_{IN}-V_{CSN}$	194	200	206	mV
$V_{CSN\_hys}$	Sense threshold hysteresis			$\pm 15$		%
$I_{CSN}$	CSN Pin Input Current	$V_{IN}-V_{CSN}=50mV$		8		$\mu A$
<b>Operating Current</b>						
$I_{SD}$	Shutdown supply current			60	100	$\mu A$
$I_{OFF}$	Quiescent supply current with output off	No Switching		0.16	0.3	mA
<b>DIM Input</b>						
$V_{DIM}$	Internal supply voltage	DIM floating		4.2		V
$V_{DIM\_H}$	DIM input voltage High			0.3	0.35	V
$V_{DIM\_HYS}$	DIM input voltage hysteresis		20	50	80	mV
$V_{DIM\_DC}$	DC brightness control		0.5		2.5	V
$F_{DIM\_MIN}$	Min. DIM Frequency			0.1		kHz
$F_{DIM\_MAX}$	Max. DIM Frequency			20		kHz
$R_{DIM}$	DIM pull up resistor to Internal supply voltage			200		K $\Omega$
$I_{DIM\_H}$	DIM input leakage high	$V_{DIM} = 5.0V$		2.8		$\mu A$
$I_{DIM\_L}$	DIM input leakage low	$V_{DIM} = 0$		22		$\mu A$
<b>Output Switch</b>						
$R_{SW}$	SW On Resistance	$V_{IN}=6V\sim 50V$		0.4		$\Omega$
$I_{SWmean}$	Continuous SW Current				1.5	A
$I_{LEAK}$	SW Leakage Current			0.5	5	$\mu A$
<b>Thermal Shutdown</b>						
$T_{SD}$	Thermal Shutdown Threshold			155		$^{\circ}C$
$T_{SD\_HYS}$	Thermal Shutdown hysteresis			20		$^{\circ}C$

**Note 4:** Typical parameters are measured at  $25^{\circ}C$  and represent the parametric norm.

**Note 5:** Datasheet min/max specification limits are guaranteed by design, test, or statistical analysis.

### SIMPLIFIED BLOCK DIAGRAM



### OPERATION DESCRIPTION

The PT4115E in conjunction with current sense resistor ( $R_{CS}$ ), the inductor ( $L1$ ), and MOSFET forms a self oscillating continuous-mode buck converter.

When input voltage  $V_{IN}$  is first applied, the initial current in  $L1$  and  $R_{CS}$  is zero and there is no output from the current sense circuit. Under this condition, the output of CS comparator is high. This turns on switch, causing current to flow from  $V_{IN}$  to ground, via  $R_{CS}$ , the LED(s),  $L1$  and internal MOSFET. The current rises at a rate determined by  $V_{IN}$  and  $L1$  to produce a voltage ramp ( $V_{CSN}$ ) across  $R_{CS}$ . When  $(V_{IN} - V_{CSN}) > 230\text{mV}$ , the output of CS comparator switches low and the switch turns off. The current flowing on the  $R_{CS}$  decreases at another rate. When  $(V_{IN} - V_{CSN}) < 170\text{mV}$ , the switch turns on again and the mean current on the LED is determined by  $200\text{mV}/R_{CS}$ .

The high-side current-sensing scheme and on-board current-setting circuitry minimize the number of external components while delivering LED current with  $\pm 3\%$  accuracy, using a 1% sense resistor. The PT4115E allows dimming with a PWM signal at the DIM input. A logic level below 0.3V at DIM forces PT4115E to turn off the LED and the logic level at DIM must be at least 2.5V to turn on the full LED current. The frequency of PWM dimming ranges from 100Hz to 20 kHz.

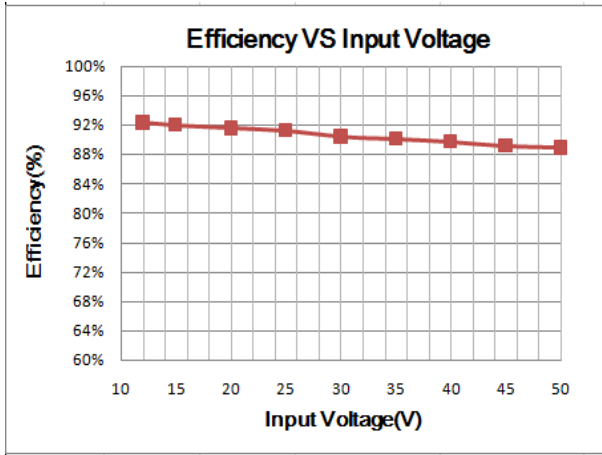
The DIM pin can be driven by an external DC voltage ( $V_{DIM}$ ) to adjust the output current to a value below the nominal average value defined by  $R_{CS}$ . The DC voltage is valid from 0.5V to 2.5V. When the DC voltage is higher than 2.5V, the output current keeps constant.

Additionally, to ensure the reliability, the PT4115E is built with a thermal shutdown (TSD) protection. The TSD protects the IC from over temperature ( $155^{\circ}\text{C}$ ).

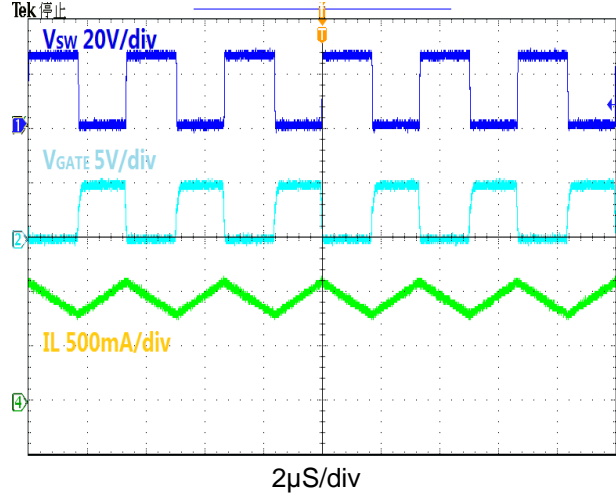
### TYPICAL PERFORMANCE CHARACTERISTICS

$V_{IN}=24V, 3LEDs, I_{OUT}=1A, T_A=25^{\circ}C$ , unless otherwise noted.

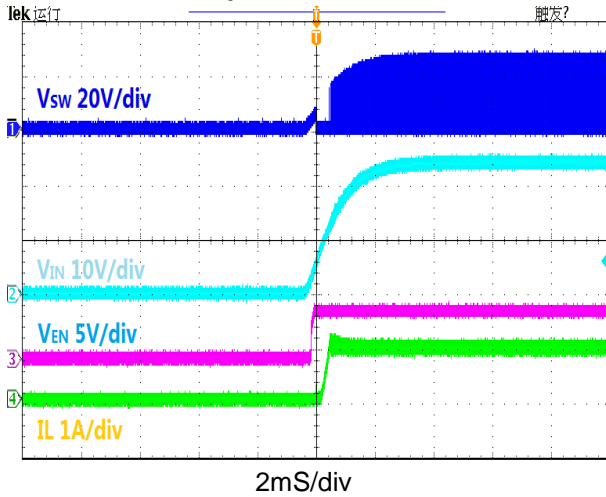
**Efficiency**



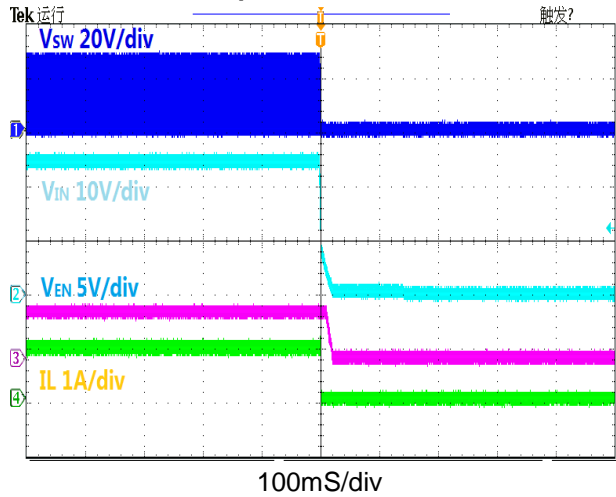
**Steady State**



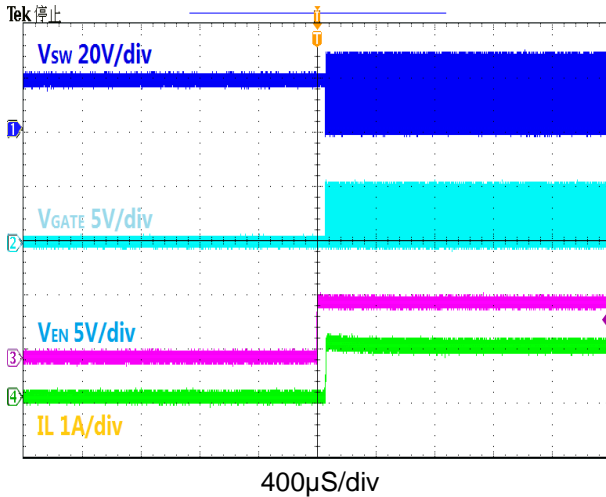
**Input Power On**



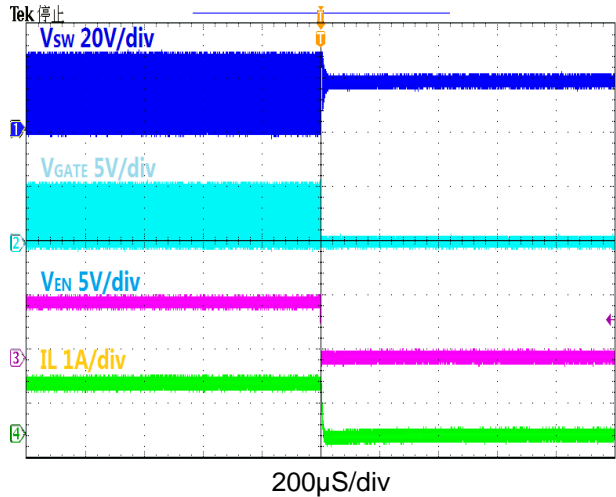
**Input Power Off**



**EN Power On**



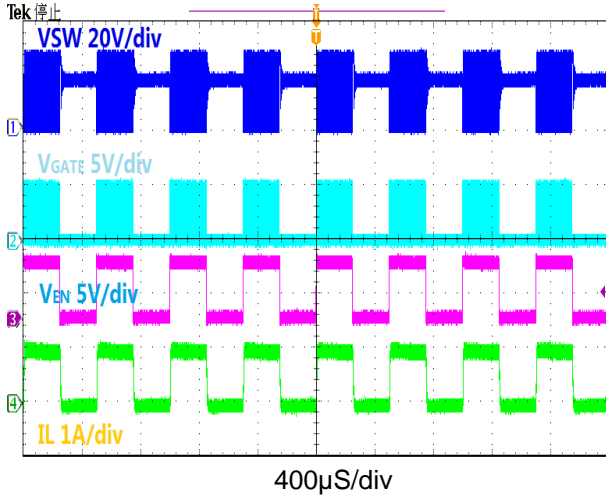
**EN Power Off**



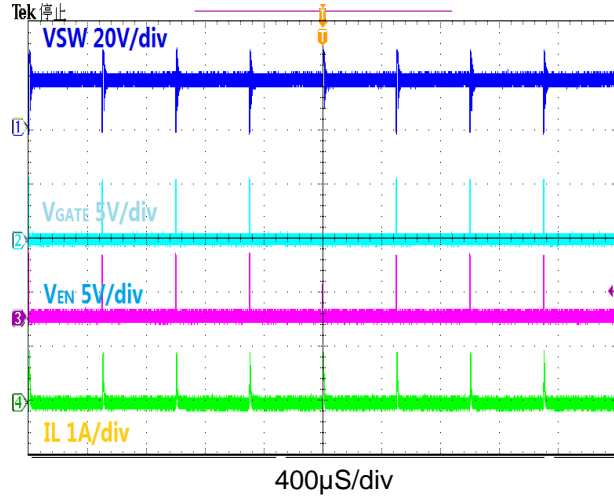
## TYPICAL PERFORMANCE CHARACTERASTICS(continued)

$V_{IN}=24V, 3LEDs, I_{OUT}=1A, T_A=25^{\circ}C$ , unless otherwise noted.

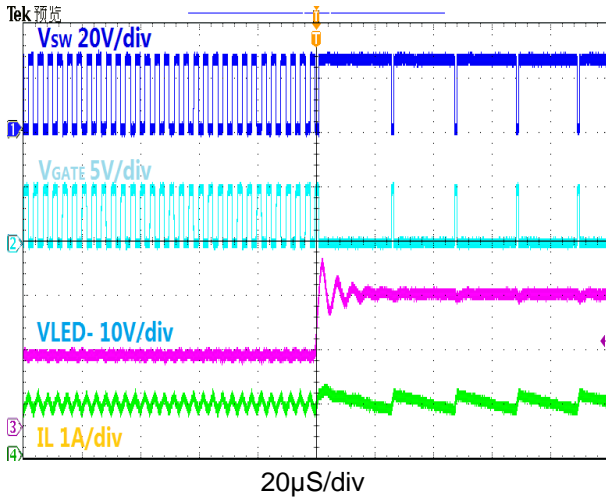
**PWM Dimming**  
(2KHz,50%)



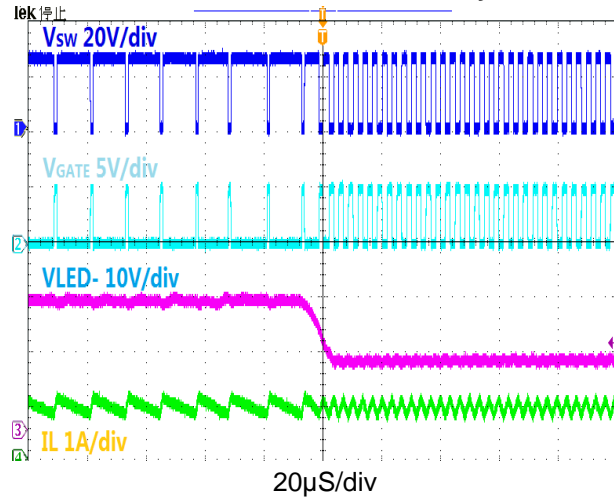
**PWM Dimming**  
(2KHz,1%)



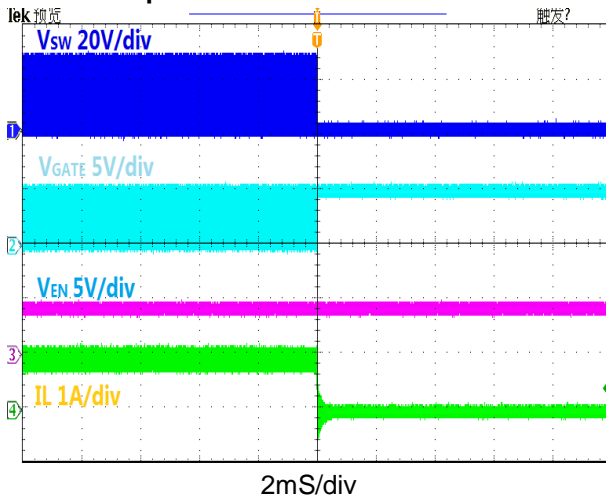
**Short LED+ to LED- Protection**



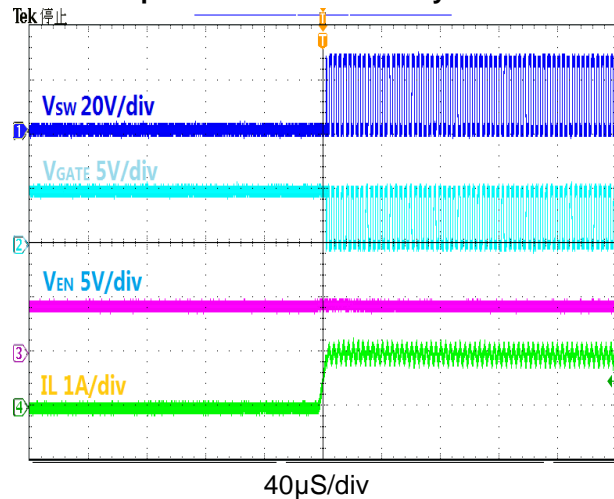
**Short LED+ to LED- Recovery**



**Open LED Load Protection**

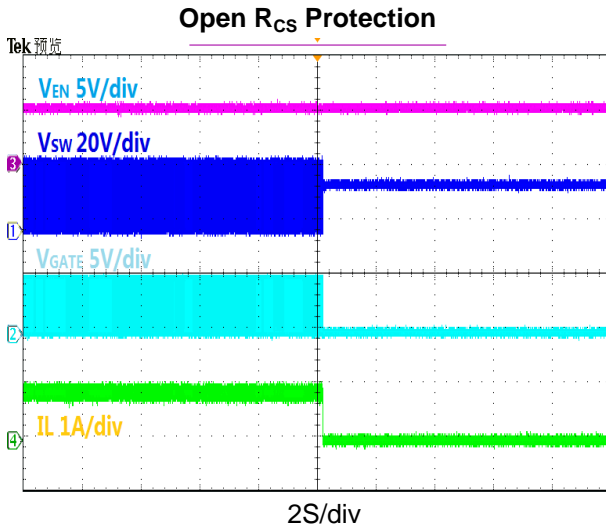


**Open LED Load Recovery**



### TYPICAL PERFORMANCE CHARACTERISTICS(continued)

$V_{IN}=24V, 3LEDs, I_{OUT}=1A, T_A=25^{\circ}C$ , unless otherwise noted.



### APPLICATION NOTES

#### Setting nominal average output current with external resistor $R_{CS}$

The nominal average output current in the LED(s) is determined by the value of the external current sense resistor ( $R_{CS}$ ) connected between  $V_{IN}$  and CSN and is given by:

$$I_{OUT}=0.2/R_{CS}$$

This equation is valid when DIM pin is float or applied with a voltage higher than 2.5V (must be less than 5V). Actually,  $R_{CS}$  sets the maximum average current which can be adjusted to a less one by dimming.

#### Output current adjustment by external DC control voltage

The DIM pin can be driven by an external DC voltage ( $V_{DIM}$ ), to adjust the output current to a value below the nominal average value defined by  $R_{CS}$ . The average output current is given by:

$$I_{OUT} = \frac{0.2 \times V_{DIM}}{2.5 \times R_{CS}} \quad (0.5V \leq V_{DIM} \leq 2.5V)$$

Note that 100% brightness setting corresponds to:  $(2.5V \leq V_{DIM} \leq 5V)$

#### Output current adjustment by PWM control

A Pulse Width Modulated (PWM) signal with duty cycle PWM can be applied to the DIM pin, to adjust the output current to a value below the nominal average value set by resistor  $R_{CS}$ :

$$I_{OUT} = \frac{0.2 \times D}{R_{CS}}$$

$$(0 \leq D \leq 100\%, 2.5V < V_{PULSE} < 5.0V)$$

$$I_{OUT} = \frac{0.2 \times D \times V_{PULSE}}{2.5 \times R_{CS}}$$

$$(0 \leq D \leq 100\%, 0 < V_{PULSE} < 2.5V)$$

PWM dimming provides reduced brightness by modulating the LED's forward current between 0% and 100%. The LED brightness is controlled by adjusting the relative ratios of the on time to the off time. A 25% brightness level is achieved by turning the LED on at full current for 25% of one cycle. To ensure this switching process between on and off state is invisible by human eyes, the switching frequency must be greater than 100 Hz. Above 100 Hz, the human eyes average the on and off times,



seeing only an effective brightness that is proportional to the LED's on-time duty cycle. The advantage of PWM dimming is that the forward current is always constant, therefore the LED color does not vary with brightness as it does with analog dimming. Pulsing the current provides precise brightness control while preserving the color purity. The dimming frequency of PT4115E can be as high as 20 kHz.

### Soft-start

An external capacitor from the DIM pin to ground will provide additional soft-start delay, by increasing the time taken for the voltage on this pin to rise to the turn-on threshold and by slowing down the rate of rise of the control voltage at the input of the comparator.

### Input capacitor selection

A low ESR capacitor should be used for input decoupling, as the ESR of this capacitor appears in series with the supply source impedance and lowers overall efficiency. This capacitor has to supply the relatively high peak current to the coil and smooth the current ripple on the input supply. A minimum value of 10 $\mu$ F is acceptable if the DC input source is close to the device, but higher values will improve performance at lower input voltages, especially when the source impedance is high. The voltage rating should be greater than the input voltage. The input capacitor should be placed as close as possible to the IC. For maximum stability over temperature and voltage, capacitors with X7R, X5R, or better dielectric are recommended. Capacitors with Y5V dielectric are not suitable for decoupling in this application and should not be used.

### Inductor selection

Lower value of inductance can result in a higher switching frequency, which causes a larger

switching loss. Choose a switch frequency between 100kHz to 500kHz for most application. According to switching frequency, inductor value can be estimated as:

$$L = \frac{(1 - V_{OUT} / V_{IN}) \times V_{OUT}}{0.3 \times I_{LED} \times f_{SW}}$$

For higher efficiency, choose an inductor with a DC resistance as small as possible.

### Output capacitor selection

For most applications, the output capacitor is not necessary. Peak to peak ripple current in the LED(s) can be reduced below 30% of the average current, if required, by adding a capacitor across the LED(s). A value of 2.2 $\mu$ F will meet most requirements. Proportionally lower ripple can be achieved with higher capacitor values. Note that the capacitor will not affect operating frequency or efficiency, but it will increase start-up delay and reduce the frequency of dimming, by reducing the rate of rise of LED voltage.

### Thermal considerations

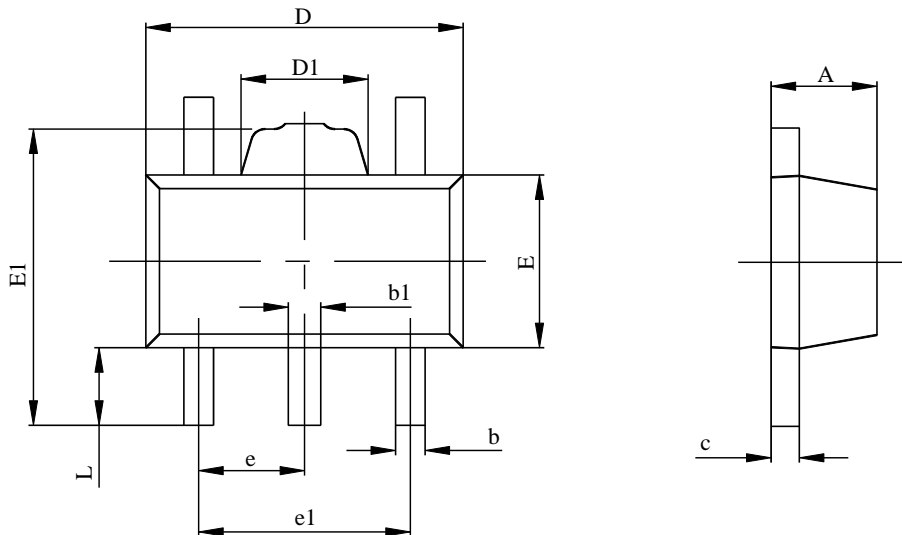
When the device operates at high ambient temperature, or when driving maximum load current, care must be taken to avoid exceeding the package power dissipation limits.

### Layout considerations

Pay careful attention to the PCB layout and component placement. R<sub>CS</sub> should be placed close to the VIN pin and CSN pin in order to minimize current sense error. The input loop including input capacitor, Schottky diode, and MOSFET which should be as short as possible.

## PACKAGE INFORMATION

### SOT89-5 Package



SYMBOL	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.360	0.560	0.014	0.022
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.400	1.800	0.055	0.071
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP.		0.060 TYP.	
e1	2.900	3.100	0.114	0.122
L	0.900	1.100	0.035	0.043

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